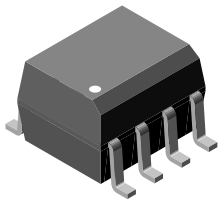
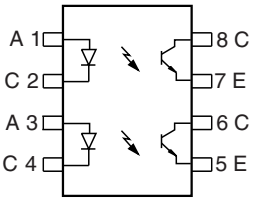
Optocoupler, Phototransistor Output, Dual Channel, SOIC-8 package



i179018



FEATURES

- Two channel coupler
- SOIC-8 surface mountable package
- Standard lead spacing of 0.05"
- Available only on tape and reel option (conforms to EIA standard 481-2)
- Isolation test voltage, 4000 V_{RMS}
- Compatible with dual wave, vapor phase and IR reflow soldering
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

Pb-free

e3

RoHS COMPLIANT

DESCRIPTION

The ILD205T/206T/207T/211T/213T/217T are optically coupled pairs with a Gallium Arsenide infrared LED and a silicon NPN phototransistor. Signal information, including a DC level, can be transmitted by the device while maintaining a high degree of electrical isolation between input and output. The ILD205T/206T/207T/211T/213T/217T come in a standard SOIC-8 small outline package for surface mounting which makes it ideally suited for high density applications with limited space. In addition to eliminating through-holes requirements, this package conforms to standards for surface mounted devices.

A specified minimum and maximum CTR allows a narrow tolerance in the electrical design of the adjacent circuits. The high BV_{CEO} of 70 V gives a higher safety margin compared to the industry standard of 30 V.

AGENCY APPROVALS

- UL1577, file no. E52744 system code Y
- CUL - file no. E52744, equivalent to CSA bulletin 5A
- DIN EN 60747-5-2 (VDE 0884) available with option 1

ORDER INFORMATION

PART	REMARKS
ILD205T	CTR 40 to 80 %, SOIC-8
ILD206T	CTR 63 to 125 %, SOIC-8
ILD207T	CTR 100 to 200 %, SOIC-8
ILD211T	CTR > 20 %, SOIC-8
ILD213T	CTR > 100 %, SOIC-8
ILD217T	CTR > 100 %, SOIC-8

ABSOLUTE MAXIMUM RATINGS (1)				
PARAMETER	**TEST CONDITION**	**SYMBOL**	**VALUE**	**UNIT**
INPUT				
Peak reverse voltage		V_R	6	V
Peak pulsed voltage	1 µs, 300 pps		1	A
Continuous forward current per channel			30	mA
Power dissipation		P_{diss}	50	mW
Derate linearly from 25 °C			0.66	mW/°C
OUTPUT				
Collector emitter breakdown voltage		BV_{CEO}	70	V
Emitter collector breakdown voltage		BV_{ECO}	7	V
Power dissipation per channel		P_{diss}	125	mW
Derate linearly from 25 °C			1.67	mW/°C
COUPLER				
Isolation test voltage	t = 1 s	V_{ISO}	4000	V_{RMS}
Total package dissipation ambient (2 LEDs and 2 detectors, 2 channels)		P_{tot}	300	mW
Derate linearly from 25 °C			4	mW/°C
Storage temperature		T_{stg}	- 55 to + 150	°C
Operating temperature		T_{amb}	- 55 to + 100	°C
Soldering time from 260 °C (2)		T_{sld}	10	s

Notes

(1) T_{amb} = 25 °C, unless otherwise specified.
Stresses in excess of the absolute Maximum Ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute Maximum Rating for extended periods of the time can adversely affect reliability.

(2) Refer to reflow profile for soldering conditions for surface mounted devices.

ELECTRICAL CHARACTERISTCS							
PARAMETER	**TEST CONDITION**	**PART**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
INPUT							
Forward voltage	I_F = 10 mA		V_F		1.2	1.55	V
Reverse current	V_R = 6 V		I_R		0.1	100	µA
Capacitance	V_R = 0 V		C_O		25		pF
OUTPUT							
Collector emitter breakdown voltage	I_C = 10 µA		BV_{CEO}	70			V
Emitter collector breakdown voltage	I_E = 10 µA		BV_{ECO}	7			V
Collector emitter leakage current	V_{CE} = 10 V, I_F = 0 A		I_{CEO}		5	50	nA
Collector emitter capacitance	V_{CE} = 0 V		C_{CE}		10		pF
COUPLER							
Collector emitter saturation voltage	I_F = 10 mA, I_C = 2.5 mA		V_{CEsat}			0.4	V
Capacitance (input to output)			C_{IO}		0.5		pF
Resistance (input to output)			R_{IO}		100		GΩ

Note

T_{amb} = 25 °C, unless otherwise specified.
Minimum and maximum values were tested requierements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
DC current transfer ratio	V_{CE} = 5 V, I_F = 10 mA	ILD205T	CTR_{DC}	40		80	%
		ILD206T	CTR_{DC}	63		125	%
		ILD207T	CTR_{DC}	100		200	%
		ILD211T	CTR_{DC}	20			%
		ILD213T	CTR_{DC}	100			%
	V_{CE} = 5 V, I_F = 1.0 mA	ILD205T	CTR_{DC}	13	30		%
		ILD206T	CTR_{DC}	22	45		%
		ILD207T	CTR_{DC}	34	70		%
		ILD217T	CTR_{DC}	100	120		%

SWITCHING CHARACTERISTICS

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Turn-on time	I_C = 2 mA, R_L = 100 Ω, V_{CC} = 5 V		t_{on}	5			µs
Turn-off time	I_C = 2 mA, R_L = 100 Ω, V_{CC} = 5 V		t_{off}	4			µs

SAFETY AND INSULATION RATINGS

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Climatic classification (according to IEC 68 part 1)				55/100/21		
Comparative tracking index		CTI	175		399	
V_{IOTM}			6000			V
V_{IORM}			560			V
P_{SO}					350	mW
I_{SI}					150	mA
T_{SI}					165	°C
Creepage			4			mm
Clearance			4			mm
Insulation thickness, reinforced rated	per IEC60950 2.10.5.1		0.2			mm

Note

As per IEC60747-5-2, §7.4.3.8.1, this optocoupler is suitable for “safe electrical insulation” only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

TYPICAL CHARACTERISTICS

T_{amb} = 25 °C, unless otherwise specified

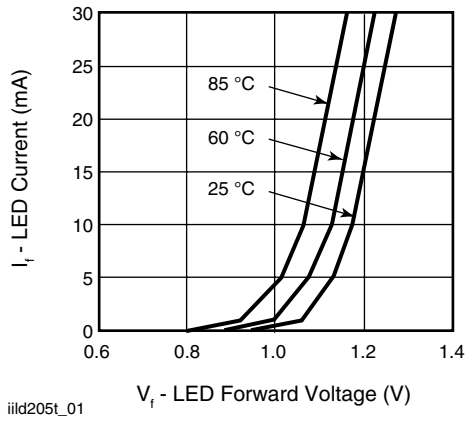


Fig. 1 - Forward Current vs. Forward Voltage

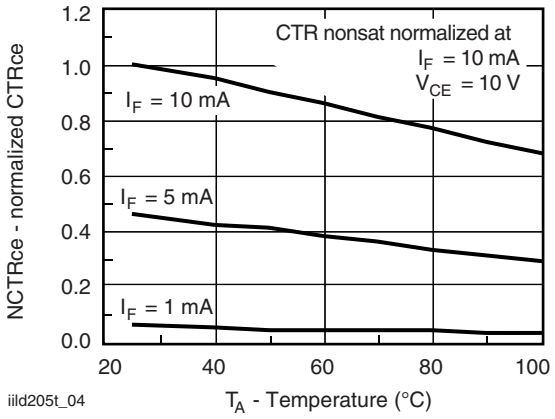


Fig. 4 - Current Transfer Ratio (normalized) vs. Ambient Temperature

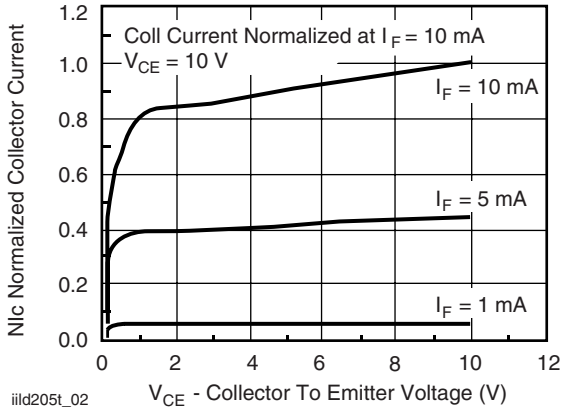


Fig. 2 - Collector Emitter Current vs. V_{CE}

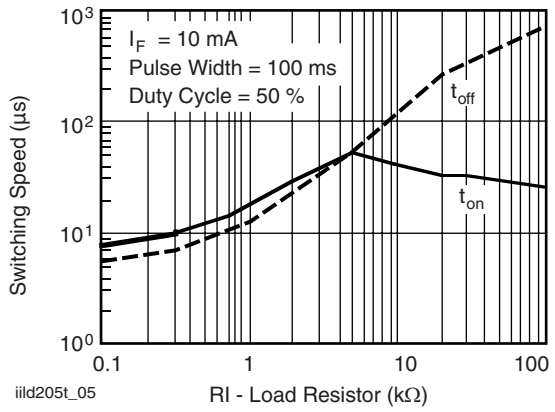


Fig. 5 - Switching Speed vs. Load Resistor

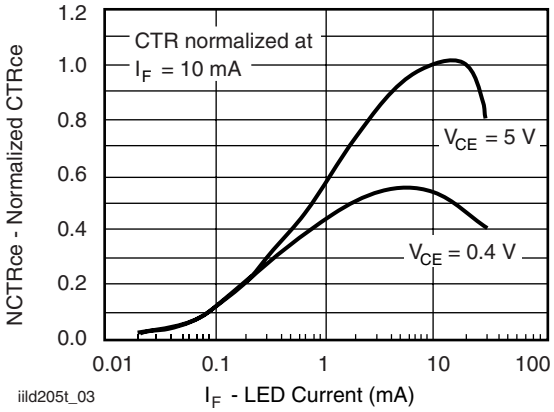


Fig. 3 - Normalized CTR_{CE} vs. Forward Current

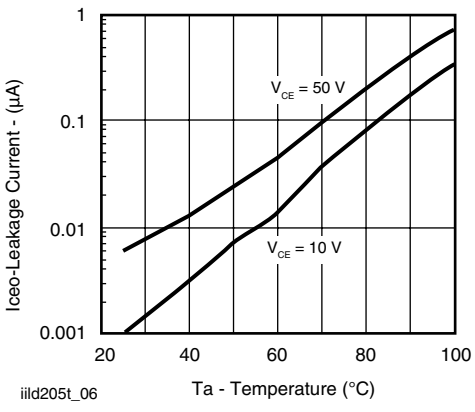


Fig. 6 - Collector Current vs. Ambient Temperature

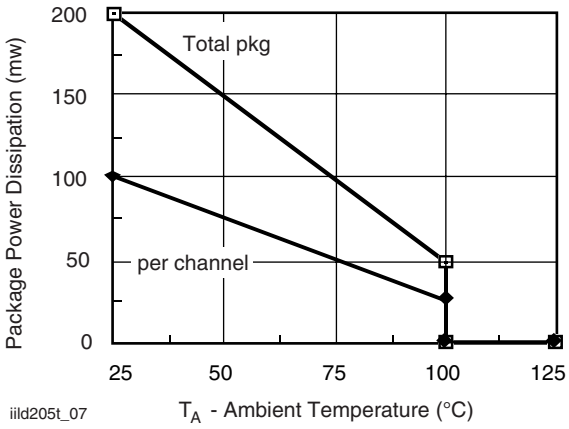


Fig. 7 - Power Dissipation vs. Ambient Temperature

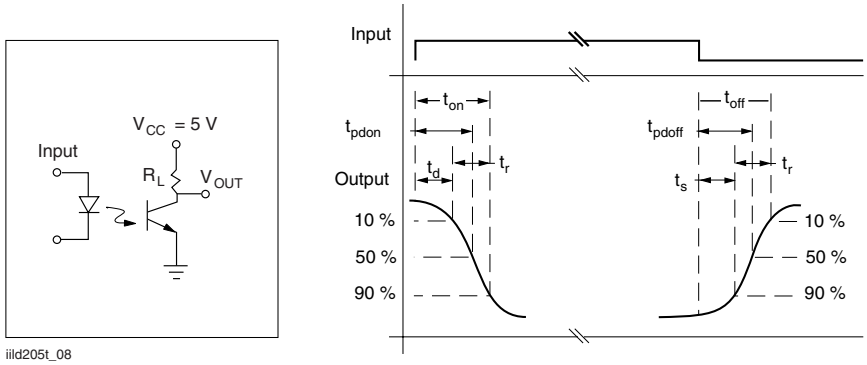
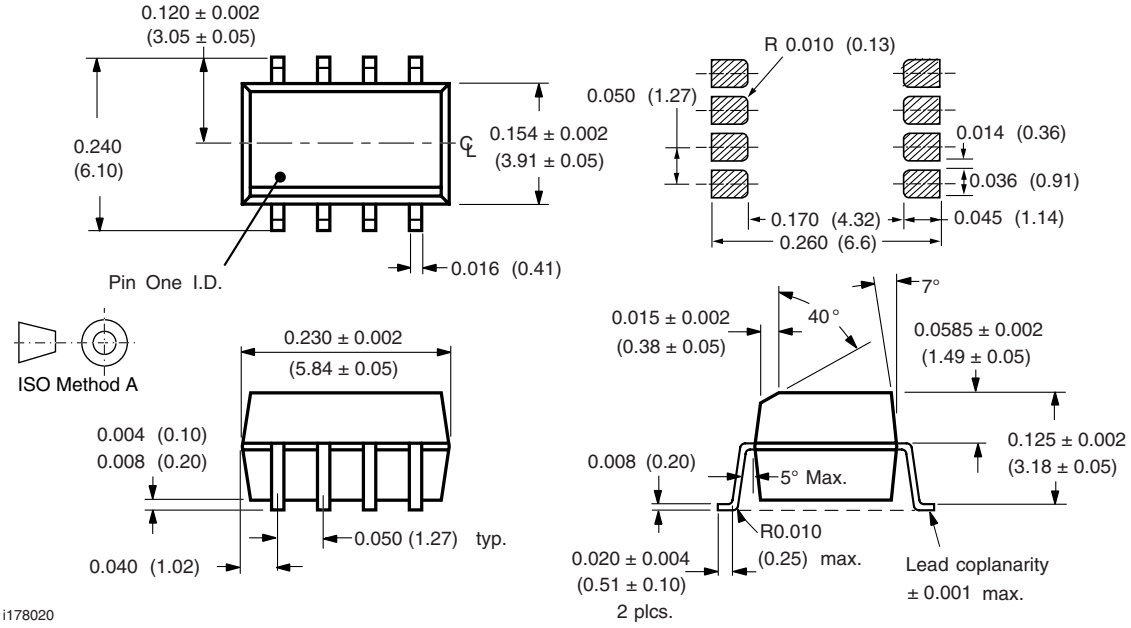


Fig. 8 Switching Test Circuit

PACKAGE DIMENSIONS in inches (millimeters)



OZONE DEPLETING SUBSTANCES POLICY STATEMENT

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany

Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, “Vishay”), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay’s terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.